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November 2014

SMBJ5V0(C)A - SMBJ170(C)A 600 Watt Transient Voltage Suppressors

Features

- · Glass-Passivated Junction
- 600 W Peak Pulse Power Capability on 10/1000 μs Waveform.
- Excellent Clamping Capability
- Low-Incremental Surge Resistance
- Fast Response Time: Typically Less than 1.0 ps from 0 V to BV minimum for Unidirectional and 5.0 ns for Bidirectional
- Typical I_R Less than 1.0 μA Above 10 V
- UL Certificate #E258596



SMB/DO-214AA

Band denotes cathode on unidirectional devices only. No band on bi-directional devices. Bi-directional types have CA suffix where electrical characteristics apply in both directions suitable for bi-directional applications.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|------------------|-------------------------------------------------------------------------------------------------------|------------|------|
| P _{PPM} | Peak Pulse Power Dissipation on 10/1000 μs Waveform | 600 | W |
| I _{PPM} | Peak Pulse Current on 10/1000 μs Waveform | See Table | Α |
| I _{FSM} | Non-Repetitive Peak Forward Surge Current Superimposed on Rated Load (JEDEC Method) ⁽¹⁾ | 100 | Α |
| T _{STG} | Storage Temperature Range | -55 to 150 | °C |
| TJ | Operating Junction Temperature Range | -55 to 150 | °C |

Note:

1. Measured on 8.3 ms single half-sine wave or equivalent square wave: duty cycle = 4 pulses per minute maximum.

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

| Uni-Directional Bi-Directional (C) Device | Part Marking ⁽²⁾ | Reverse Stand-Off Voltage V _{RWM} (V) | Vol | kdown tage kg (V) Max. | Test Current I _T (mA) | Clamping Voltage at I _{PPM} V _C (V) | Peak Pulse Current I _{PPM} (A) | Reverse Leakage at V _{RWM} I _R (μΑ) ⁽³⁾ |
|-------------------------------------------------|--------------------------------|---------------------------------------------------------|------|---------------------------------|----------------------------------------|------------------------------------------------------------------|-----------------------------------------------|---------------------------------------------------------------------------------|
| SMBJ5V0(C)A | KE | 5.0 | 6.40 | 7.00 | 10 | 9.2 | 65.2 | 800 |
| SMBJ6V0(C)A | KG | 6.0 | 6.67 | 7.37 | 10 | 10.3 | 58.3 | 800 |
| SMBJ6V5(C)A | KK | 6.5 | 7.22 | 7.98 | 10 | 11.2 | 53.6 | 500 |
| SMBJ7V0(C)A | KM | 7.0 | 7.78 | 8.60 | 10 | 12.0 | 50.0 | 200 |
| SMBJ7V5(C)A | KP | 7.5 | 8.33 | 9.21 | 1 | 12.9 | 46.5 | 100 |
| SMBJ8V0(C)A | KR | 8.0 | 8.89 | 9.83 | 1 | 13.6 | 44.1 | 50 |
| SMBJ8V5(C)A | KT | 8.5 | 9.44 | 10.4 | 1 | 14.4 | 41.7 | 20 |
| SMBJ9V0(C)A | KV | 9.0 | 10.0 | 11.1 | 1 | 15.4 | 39.0 | 10 |
| SMBJ10(C)A | KX | 10 | 11.1 | 12.8 | 1 | 17.0 | 35.3 | 5 |
| SMBJ11(C)A | KZ | 11 | 12.2 | 13.5 | 1 | 18.2 | 33.0 | 5 |
| SMBJ12(C)A | LE | 12 | 13.3 | 14.7 | 1 | 19.9 | 30.2 | 5 |
| SMBJ13(C)A | LG | 13 | 14.4 | 15.9 | 1 | 21.5 | 27.9 | 5 |
| SMBJ14(C)A | LK | 14 | 15.6 | 17.2 | 1 | 23.2 | 25.9 | 5 |
| ` ′ | | | | | | | | |
| SMBJ15(C)A | LM LP | 15 | 16.7 | 18.5 | 1 | 24.4 | 24.6 23.1 | 5 5 |
| SMBJ16(C)A | | 16 | 17.8 | 19.7 | | 26.0 | | |
| SMBJ17(C)A | LR | 17 | 18.9 | 20.9 | 1 | 27.6 | 21.7 | 5 |
| SMBJ18(C)A | LT | 18 | 20.0 | 22.1 | 1 | 29.2 | 20.5 | 5 |
| SMBJ20(C)A | LV | 20 | 22.2 | 24.5 | 1 | 32.4 | 18.5 | 5 |
| SMBJ22(C)A | LX | 22 | 24.4 | 26.9 | 1 | 35.5 | 16.9 | 5 |
| SMBJ24(C)A | LZ | 24 | 26.7 | 29.5 | 1 | 38.9 | 15.4 | 5 |
| SMBJ26(C)A | ME | 26 | 28.9 | 31.9 | 1 | 42.1 | 14.3 | 5 |
| SMBJ28(C)A | MG | 28 | 31.1 | 34.4 | 1 | 45.4 | 13.2 | 5 |
| SMBJ30(C)A | MK | 30 | 33.3 | 36.8 | 1 | 48.4 | 12.4 | 5 |
| SMBJ33(C)A | MM | 33 | 36.7 | 40.6 | 1 | 53.3 | 11.3 | 5 |
| SMBJ36(C)A | MP | 36 | 40.0 | 44.2 | 1 | 58.1 | 10.3 | 5 |
| SMBJ40(C)A | MR | 40 | 44.4 | 49.1 | 1 | 64.5 | 9.3 | 5 |
| SMBJ43(C)A | MT | 43 | 47.8 | 52.8 | 1 | 69.4 | 8.6 | 5 |
| SMBJ45(C)A | MV | 45 | 50.0 | 55.3 | 1 | 72.7 | 8.3 | 5 |
| SMBJ48(C)A | MX | 48 | 53.3 | 58.9 | 1 | 77.4 | 7.8 | 5 |
| SMBJ51(C)A | MZ | 51 | 56.7 | 62.7 | 1 | 82.4 | 7.3 | 5 |
| SMBJ54(C)A | NE | 54 | 60.0 | 66.3 | 1 | 87.1 | 6.9 | 5 |
| SMBJ58(C)A | NG | 58 | 64.4 | 71.2 | 1 | 93.6 | 6.4 | 5 |
| SMBJ60(C)A | NK | 60 | 66.7 | 73.7 | 1 | 96.8 | 6.2 | 5 |
| SMBJ64(C)A | NM | 64 | 71.1 | 78.6 | 1 | 103.0 | 5.8 | 5 |
| SMBJ70(C)A | NP | 70 | 77.8 | 86.0 | 1 | 113.0 | 5.3 | 5 |
| SMBJ75(C)A | NR | 75 | 83.3 | 92.1 | 1 | 121.0 | 5.0 | 5 |
| SMBJ78(C)A | NT | 78 | 86.7 | 95.8 | 1 | 126.0 | 4.8 | 5 |

Notes:

- 2. Color band denotes cathode on unidirectional devices only. No color band on bidirectional devices.
- 3. For bidirectional parts with V_{RWM} < 10 V, the I_R max limit is doubled.

Electrical Characteristics (Continued)

Values are at $T_A = 25$ °C unless otherwise noted.

| Uni-Directional Bi-Directional (C) Device | Part Marking ⁽²⁾ | Reverse Stand-Off Voltage V _{RWM} (V) | Breakdown Voltage V _{BR} (V) | | Test Current | Clamping Voltage at I _{PPM} | Peak Pulse Current | Reverse Leakage at V _{RWM} |
|-------------------------------------------------|--------------------------------|---------------------------------------------------------|---------------------------------------------|-------|---------------------|--------------------------------------------|-----------------------|-------------------------------------------|
| Device | | | Min. | Max. | I _T (mA) | V _C (V) | I _{PPM} (A) | I _R (μΑ) ⁽³⁾ |
| SMBJ85(C)A | NV | 85 | 94.4 | 104.0 | 1 | 137.0 | 4.4 | 5 |
| SMBJ90(C)A | NX | 90 | 100.0 | 111.0 | 1 | 146.0 | 4.1 | 5 |
| SMBJ100(C)A | NZ | 100 | 111.0 | 123.0 | 1 | 162.0 | 3.7 | 5 |
| SMBJ110(C)A | PE | 110 | 122.0 | 135.0 | 1 | 177.0 | 3.4 | 5 |
| SMBJ120(C)A | PG | 120 | 133.0 | 147.0 | 1 | 193.0 | 3.1 | 5 |
| SMBJ130(C)A | PK | 130 | 144.0 | 159.0 | 1 | 209.0 | 2.9 | 5 |
| SMBJ150(C)A | PM | 150 | 167.0 | 185.0 | 1 | 243.0 | 2.5 | 5 |
| SMBJ160(C)A | PP | 160 | 178.0 | 197.0 | 1 | 259.0 | 2.3 | 5 |
| SMBJ170(C)A | PR | 170 | 189.0 | 209.0 | 1 | 275.0 | 2.2 | 5 |

Notes:

- 2. Color band denotes cathode on unidirectional devices only. No color band on bidirectional devices.
- 3. For bidirectional parts with $\rm V_{RWM}$ < 10 V, the $\rm I_{R}$ max limit is doubled.

Typical Performance Characteristics

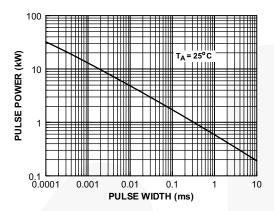


Figure 1. Peak Pulse Power Rating Curve

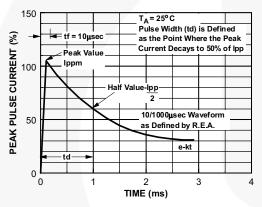


Figure 3. Pulse Waveform

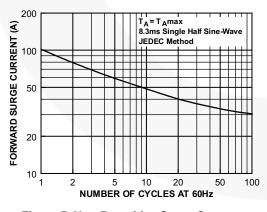


Figure 5. Non-Repetitive Surge Current

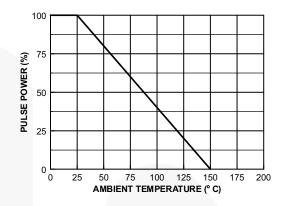


Figure 2. Pulse Derating Curve

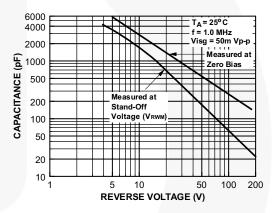
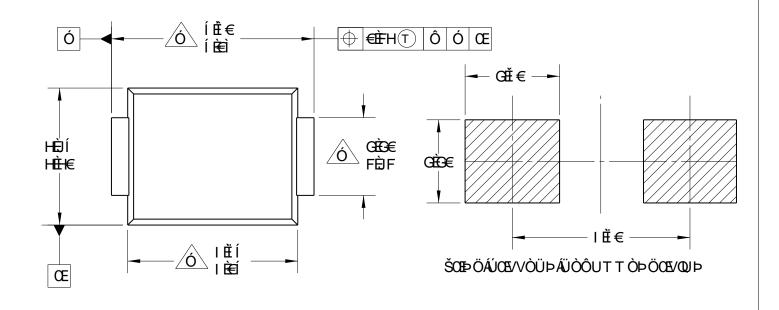
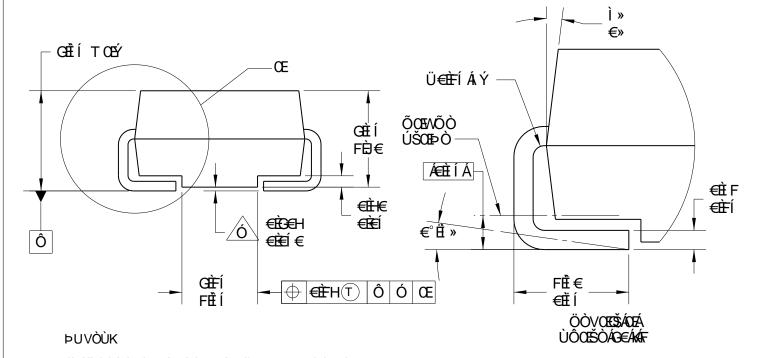


Figure 4. Junction Capacitance

| ÚÞÞÚ | | | | | |
|------|-----------------|-----------|-------------|--|--|
| ÞÓÜ | ĠÒÙÔÜŴVWÞ | ÖŒVÒ | ÓŸÐÐÐÚŰÖ | | |
| F | ÜÒŠÒŒÙÒÖÁ/UÁÖÔÔ | FJT ŒŸŒ€Ì | ÙÖŠÒÒÆÓÐÚÙZ | | |





ÁKOEÁÒÝ ÔÒÚVÁY PÒÜÒÁÞUVÒÖÁÔUÞØUÜT ÙÁVUÁ
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ÁKÖEÄÖCT ÒÞÙŒJÞÙÁDEJÒÁÒÝÔŠWÙCKÒÁJØÁÓWÜÜÜÈ
ÁT UŠÖÁZŠCEÙPÁDEÞÖÁVÐÁÓCEJÁJÜUVVÜWÙŒJÞÙÈ
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|---------------------------------|-------------------|----------------------------|-----------------------|---------|-------|----------|
| ^{ÔPÔÔSÔÔK} ÙÖÆSÒÒ | | SE | MICO | NDUCTO | ₩ | |
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| œúūuxòök PUY ŒÜÖÁŒŠŠÒÞ | | ÖUGFIÁXŒÜQŒVQUÞÁŒŒ | | | | |
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| ØÔP | | ØUÜTÖÜŠŸK ÞÐŒ ÚPÒÒVÁK FÁJØ | | | ÁUØÁF | |

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